

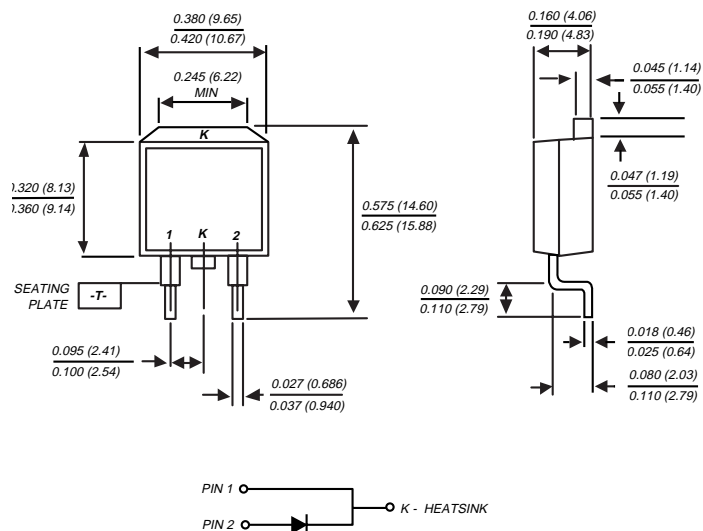
FESB16AT THRU FESB16JT

FAST EFFICIENT PLASTIC RECTIFIER

Reverse Voltage - 50 to 600 Volts

Forward Current - 16.0 Amperes

TO-263AA



Dimensions in inches and (millimeters)

FEATURES

- ◆ Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- ◆ Glass passivated chip junction
- ◆ Low power loss
- ◆ Low forward voltage, high current capability
- ◆ High surge current capability
- ◆ Superfast recovery time, for high efficiency
- ◆ High temperature soldering in accordance with CECC 802 / Reflow guaranteed



MECHANICAL DATA

Case: JEDEC TO-263AA molded plastic body over passivated chips

Terminals: Plated lead solderable per MIL-STD-750, Method 2026

Polarity: As marked

Mounting Position: Any

Weight: 0.08 ounce, 2.24 grams

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

	SYMBOLS	FESB 16AT	FESB 16BT	FESB 16CT	FESB 16DT	FESB 16FT	FESB 16GT	FESB 16HT	FESB 16JT	UNITS	
Maximum repetitive peak reverse voltage	V_{RRM}	50	100	150	200	300	400	500	600	Volts	
Maximum RMS voltage	V_{RMS}	35	70	105	140	210	280	350	420	Volts	
Maximum DC blocking voltage	V_{DC}	50	100	150	200	300	400	500	600	Volts	
Maximum average forward rectified current at $T_C=100^\circ\text{C}$	$I_{(AV)}$	16.0								Amps	
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method) at $T_C=100^\circ\text{C}$	I_{FSM}	250.0								Amps	
Maximum instantaneous forward voltage at 16A	V_F	0.975			1.3		1.5			Volts	
Maximum DC reverse current at rated DC blocking voltage	I_R	$T_C=25^\circ\text{C}$ 10.0			$T_C=100^\circ\text{C}$ 500.0			μA			
Maximum reverse recovery time (NOTE 1)	t_{rr}	35.0			50.0			ns			
Typical junction capacitance (NOTE 2)	C_J	175.0					145.0				pF
Typical thermal resistance (NOTE 3)	$R_{\theta JC}$	1.2								$^\circ\text{C/W}$	
Operating and storage temperature range	T_J, T_{STG}	-65 to +150								$^\circ\text{C}$	

NOTES:

- (1) Reverse recovery test conditions: $I_F=0.5\text{A}$, $I_R=1.0\text{A}$, $I_{rr}=0.25\text{A}$
- (2) Measured at 1.0 MHz and applied reverse voltage of 4.0 Volts
- (3) Thermal resistance from junction to case

NOTICE: Advanced product information is subject to change without notice

RATINGS AND CHARACTERISTICS CURVES FESB16AT THRU FESB16JT

FIG. 1 - FORWARD CURRENT DERATING CURVE

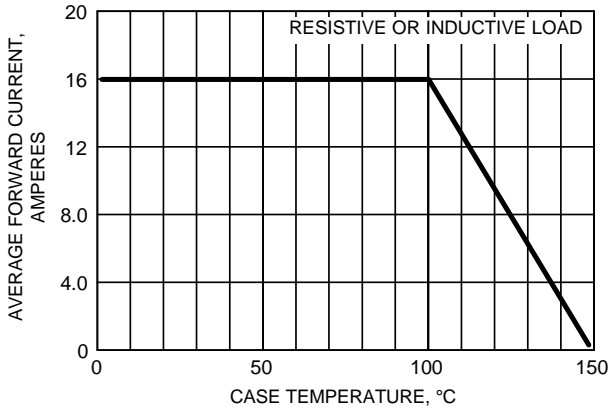


FIG. 2 - MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

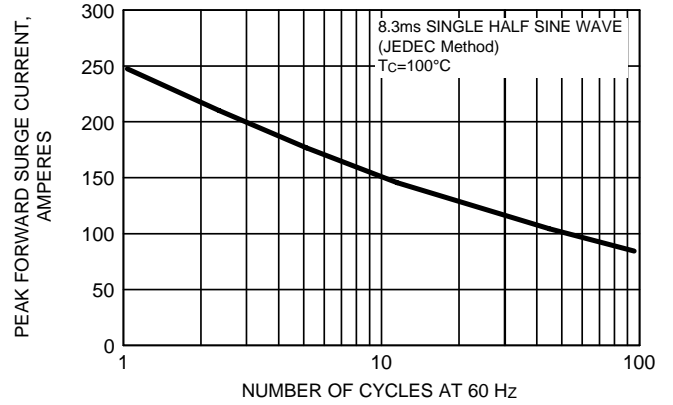


FIG. 4 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

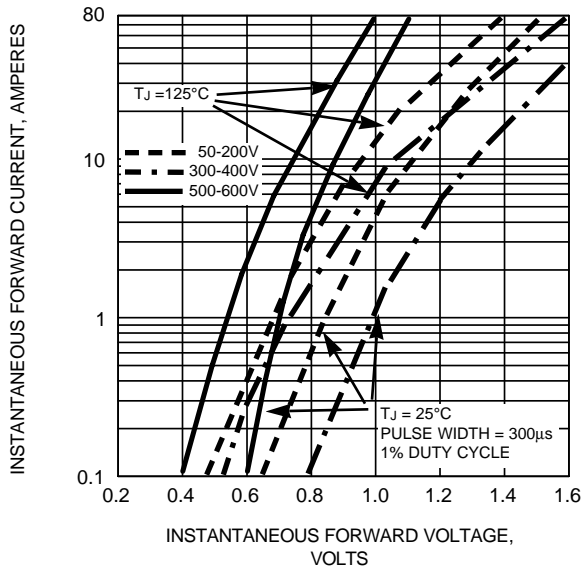


FIG. 3 - TYPICAL REVERSE CHARACTERISTICS

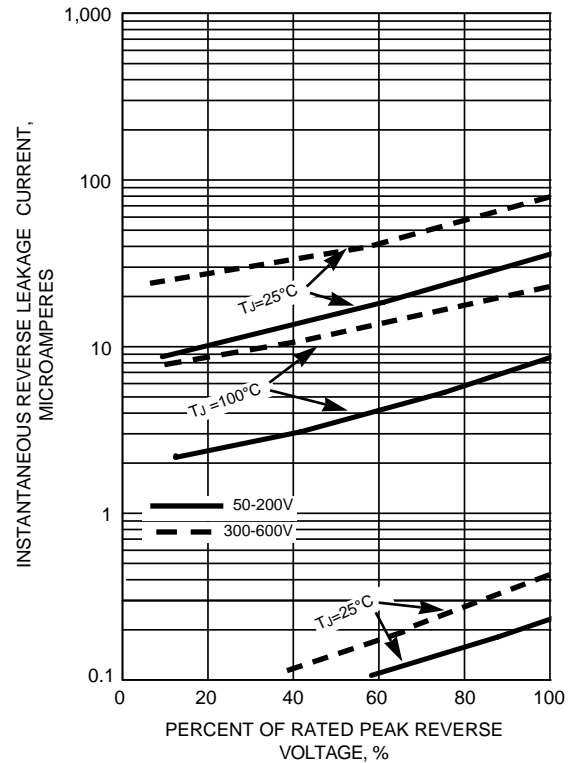


FIG. 5 - TYPICAL JUNCTION CAPACITANCE

